Icemos Technology Ltd Product Specification 1000.736301 Issue Date 18 May 2023 16:51:10

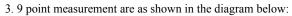
Part Number	Customer

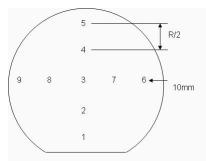
Category	Parameter		Specification	Measurement Method	
OverallWafer	1.0	Diameter	150.00 +/- 0.20 mm		
	2.0	Primary Flat Orientation	{110} +/- 1.0 degree	Wafer Vendor	
	3.0	Primary Flat Length	57.50 +/- 2.50 mm	Wafer Vendor	
	4.0	Secondary Flat Orientation	none	Wafer Vendor	
	5.0	Overall Thickness	438.50 +/- 6.00 μm	ADE, 100%	
	6.0	Total Thickness Variation (TTV)	<3.00μm	Guaranteed by Process	
	7.0	Bow	<60.00μm	ADE to ASTM F534, 100%	
	8.0	Warp	<60.00μm	ADE to ASTM F534, 100%	
	9.0	Edge Chips	0	Bright Light, 100%	
	10.0	Edge Exclusion	5mm		
	11.0	Bond Process	Fusion Bonding	Guaranteed by Process	
HandleSilicon	12.0	Handle Growth Method	CZ	Wafer Vendor	
	13.0	Handle Orientation	{100} +/- 0.5 degree	Wafer Vendor	
	14.0	Handle Thickness	400.00 +/- 5.00 μm	ADE, 100%	
	15.0	Handle Doping Type	P	Wafer Vendor	
	16.0	Handle Dopant	Boron	Wafer Vendor	
	17.0	Handle Resistivity	1~20 Ohmem	Wafer Vendor	
	18.0	Backside Finish	Polished with oxide, lasermark, and light handling marks	Guaranteed by process	
BuriedOxide	19.0	Oxide Type	Thermal		
	20.0	Oxide Thickness	5,000.00 +/- 250.00 A	Nanospec centre point, 4%	
	21.0	Oxide formed on	Handle or/and Device		
DeviceSilicon	22.0	Device Growth Method	CZ	Wafer Vendor	
	23.0	Device Orientation	{100} +/- 0.5 degree	Wafer Vendor	
	24.0	Nominal Thickness	38.00 +/- 0.50 μm	Filmetrics 9pts, 100% (note3)	
	25.0	Distance to device silicon edge from wafer edge	< 2mm	Typical by Process	
	26.0	Device Doping Type	N	Wafer Vendor	
	27.0	Device Dopant	Phosphorous	Wafer Vendor	
	28.0	Device Resistivity	0.4~1.15 Ohmem	Wafer Vendor	
	29.0	Surface Voids	None	Bright Light, 100% (note2)	
	30.0	Haze	None	Bright Light, 100% (note2)	
	31.0	Scratches	none on the front-side	Bright Light, 100% (note2)	

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Part Number		Customer		
Category	Parameter	Specification	Measurement Method	
Shipping Details	Wafer per box :	Max 25		
	Packaging:	Taped Polypropylene Wafer Box Empak, Ultrapak, 150.00mm Antistatic Double Bagging		
	Lot Shipment Data	Device Thickness Bow / Warp Data Handle and SOI Thickness		
Explanatory Notes	1. Microscope inspec	etion performed using microscope scan as below. 5x objective.		
	2. All bright light inspections performed exclude all wafer area outside the edge exclusion defined in Overall			

2. All bright light inspections performed exclude all wafer area outside the edge exclusion defined in Overal Wafer, Edge Exclusion. High intensity bright lamp inspection as per ASTM F523.





Additional Information